

180 W, DC - 2.0 GHz, 50 V, GaN HEMT

Description

Cree's CGHV40180P is an unmatched, gallium nitride (GaN) high electron mobility transistor (HEMT). The CGHV40180P, operating from a 50 volt rail, offers a general purpose, broadband solution to a variety of RF and microwave applications. GaN HEMTs offer high efficiency, high gain and wide bandwidth capabilities making the CGHV40180P ideal for linear and compressed amplifier circuits. The transistor is available in a 2-lead pill package.



Package Types: 440206 PN: CGHV40180P

Typical Performance Over 800 MHz - 1000 MHz (T _c = 25°C), 50 V						
Parameter	800 MHz	850 MHz	900 MHz	950 MHz	100	

5.6	25.2	24.6			
		24.0	24.4	24.3	dB
0.4	20.8	20.4	20.1	20.1	dB
.75	302	275	257	257	W
57	75	76	73	71	%
7			5 302 275	5 302 275 257	5 302 275 257 257

Notes: Measured CW in the CGHV40180P-AMP Application circuit

Features

- Up to 2.0 GHz Operation
- 24 dB Small Signal Gain at 900 MHz
- 20 dB Power Gain at 900 MHz
- 250 W Typical Output Power at 900 MHz
- 75% Efficiency at P_{SAT}

Applications

- **Military Communications**
- Public Safety VHF-UHF applications
- Radar
- Medical
- **Broadband Amplifiers**



Large Signal Models Available for ADS and MWO

Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V _{DSS}	150	Volts	25°C
Gate-to-Source Voltage	V _{GS}	-10, +2	Volts	25°C
Storage Temperature	T _{STG}	-65, +150	°C	
Operating Junction Temperature ¹	Tj	225	°C	
Maximum Forward Gate Current	I _{GMAX}	42	mA	25°C
Maximum Drain Current ¹	I _{DMAX}	12.1	A	25°C
Soldering Temperature ²	T _s	245	°C	
CGHV40180P Thermal Resistance, Junction to Case	R _{ejc}	0.87	°C/W	P _{DISS} = 150, 85°C
Maximum dissipated power		150	W	P _{DISS} = 150, 85°C
Case Operating Temperature ³	T _c	-40, +150	°C	

Notes:

 $^{\rm 1}\,{\rm Current}$ limit for long term, reliable operation

² Refer to the Application Note on soldering at <u>wolfspeed.com/rf/document-library</u>

³ See also, Power Derating Curve on Page 5

Electrical Characteristics

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics ¹ ($T_c = 25$ °C)						
Gate Threshold Voltage	V _{GS(th)}	-3.8	-3.0	-2.3	V _{DC}	$V_{\rm DS} = 10 \text{ V}, \text{ I}_{\rm D} = 41.8 \text{ mA}$
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.7	-	V _{DC}	$V_{\rm DS} = 50 \text{ V}, \text{ I}_{\rm D} = 1000 \text{ mA}$
Saturated Drain Current ²	I _{DS}	31.4	37.6	-	А	$V_{\rm DS} = 6.0 \text{ V}, V_{\rm GS} = 2.0 \text{ V}$
Drain-Source Breakdown Voltage	V _{BR}	125	-	-	V _{DC}	$V_{gs} = -8 \text{ V}, I_{p} = 41.8 \text{ mA}$
RF Characteristics ³ ($T_c = 25^{\circ}C, F_0 =$	900 MHz un	ess otherv	vise noted)			
Small Signal Gain	G _{ss}	22.8	24.0	-	dB	$V_{_{DD}} = 50 \text{ V}, \text{ I}_{_{DQ}} = 1.0 \text{ A}, \text{ P}_{_{in}} = 10 \text{ dBm CW}$
Power Gain	G _P	18.4	19.8	-	dB	$V_{DD} = 50 \text{ V}, \text{ I}_{DQ} = 1.0 \text{ A}, \text{ P}_{in} = 34 \text{ dBm CW}$
Power Output at Saturation	P _{out}	52.6	53.9	-	dBm	$V_{DD} = 50 \text{ V}, \text{ I}_{DQ} = 1.0 \text{ A}, \text{ P}_{in} = 34 \text{ dBm CW}$
Drain Efficiency⁴	η	59	69	-	%	$V_{DD} = 50 \text{ V}, \text{ I}_{DQ} = 1.0 \text{ A}, \text{ P}_{in} = 34 \text{ dBm CW}$
Output Mismatch Stress	VSWR	-	_	3:1	Ψ	No damage at all phase angles, $V_{DD} = 50 \text{ V}, \text{ I}_{DQ} = 1.0 \text{ A}, \text{ P}_{OUT} = 180 \text{ W CW}$
Dynamic Characteristics						
Input Capacitance	C _{GS}	-	57.8	-	pF	$V_{_{DS}} = 50 \text{ V}, V_{_{gs}} = -8 \text{ V}, \text{ f} = 1 \text{ MHz}$
Output Capacitance	C _{DS}	-	13.7	-	pF	$V_{_{DS}} = 50 \text{ V}, V_{_{gs}} = -8 \text{ V}, \text{ f} = 1 \text{ MHz}$
Feedback Capacitance	C _{GD}	-	1.23	-	pF	$V_{DS} = 50 \text{ V}, V_{gs} = -8 \text{ V}, \text{ f} = 1 \text{ MHz}$

Notes:

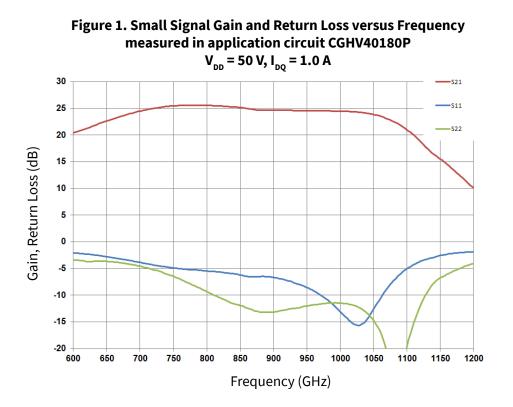
¹ Measured on wafer prior to packaging

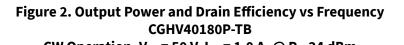
² Scaled from PCM data

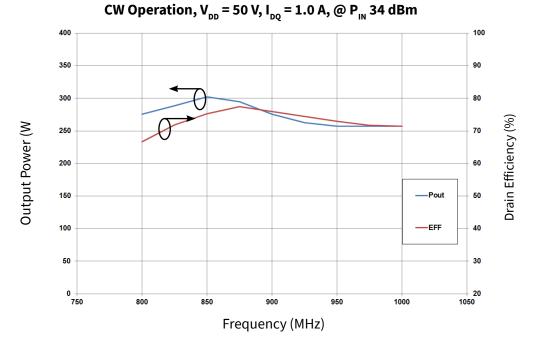
³ Measurements are to be performed using Cree production test fixture AD-838292P-TB

⁴ Drain Efficiency = P_{OUT}/PDC

CGHV40180P Typical Performance







CGHV40180P Typical Performance

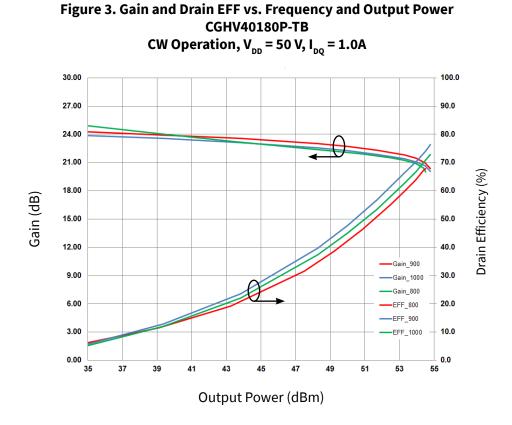
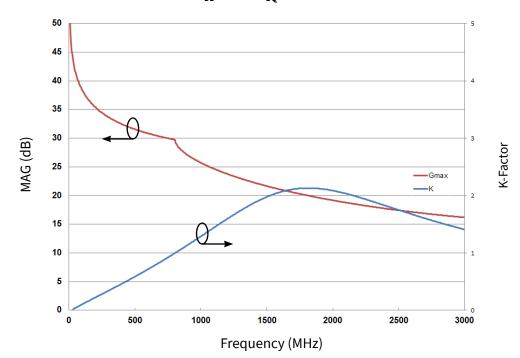


Figure 4. Simulated Maximum Available Gain and K-factor of the CGHV40180P $V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 1.0 A



CGHV40180P Power Dissipation De-rating Curve

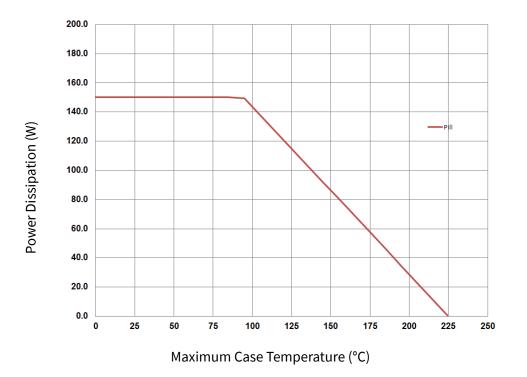
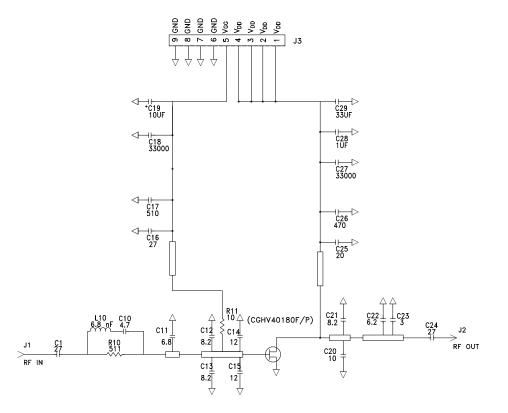
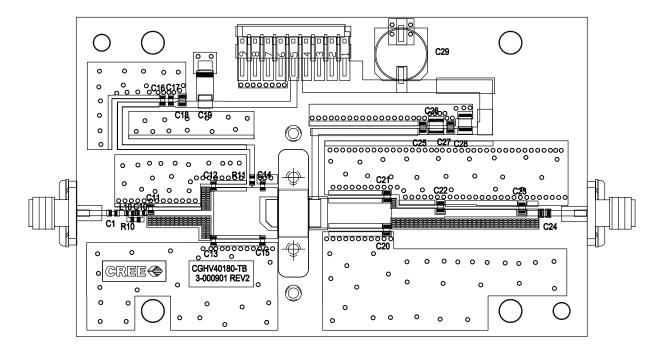


Figure 5. Transient Power Dissipation De-rating Curve

CGHV40180P-AMP Application Circuit Schematic



CGHV40180P-AMP Application Circuit

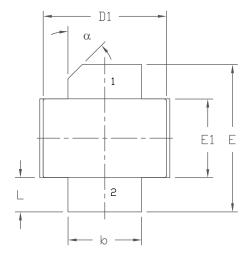


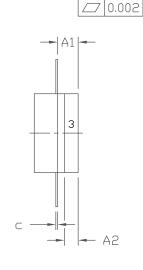
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CGHV40180P-AMP Application Circuit Bill of Materials

R11 RES, 1/16W, 0603, 1%, 10.0 OHMS 1 R10 RES, 1/16W, 0603, 1%, 511 OHMS 1 C29 CAP, 33UF, 20%, 6 CASE 1 C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25 pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 1 C14, C15 CAP, 3000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C21 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CA	Designator	Description	Qty
C29 CAP, 33UF, 20%, G CASE 1 C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 3000pF, 0805, 100V, X7R 2 C20 CAP, 20pF, ±5%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C24 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C22	R11	RES, 1/16W, 0603, 1%, 10.0 OHMS	1
C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C11 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 3000pF, 0805, 100V, X7R 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C22	R10	RES, 1/16W, 0603, 1%, 511 OHMS	1
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C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C24 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 J. PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1	C28	CAP 1.0UF, 100V, ±10%, X7R, 1210	1
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C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C24 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C22 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ.1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-143	C26	CAP, 470pF, NPO, 5%, 250V, ATC800B	1
C1, C16CAP, 27pF, ±5%, 0603, ATC600S2C10CAP, 4.7pF, ±0.1pF, 0603, ATC600S1C11CAP, 6.8pF, ±0.25pF, 0603, ATC600S1C12, C13CAP, 8.2pF, ±0.25 pF, 0603, ATC600S2C18, C27CAP, 33000pF, 0805, 100V, X7R2C20CAP, 10pF, ±1%, 250V, 0805, ATC600F2C25CAP, 20pF, ±5%, 250V, 0805, ATC600F1C24CAP, 27pF, ±5%, 250V, 0805, ATC600F1C23CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F2C21CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F1-PCB ROGERS HTC6035, 0.020 THK, ER 3.601J1,J2CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST2J3HEADER RT>PLZ .1CEN LK 9POS1L10INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND1	C19	CAP, 10UF, 16V TANTALUM, 2312	1
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C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C11	CAP, 6.8pF, ±0.25pF, 0603, ATC600S	1
C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805, ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C12, C13	CAP, 8.2pF, ±0.25 pF, 0603, ATC600S	2
C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C18, C27	CAP, 33000pF, 0805, 100V, X7R	2
C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1 C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C20	CAP, 10pF, ±1%, 250V, 0805, ATC600F	2
C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2 C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C25	CAP, 20pF, ±5%, 250V, 0805, ATC600F	1
C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1 C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C24	CAP, 27pF, ±5%, 250V, 0805, ATC600F	1
C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1 - PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ.1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C23	CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F	2
- PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1 J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C22	CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F	1
J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2 J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	C21	CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F	1
J3 HEADER RT>PLZ .1CEN LK 9POS 1 L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	-	PCB ROGERS HTC6035, 0.020 THK, ER 3.60	1
L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1	J1,J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST	2
	J3	HEADER RT>PLZ .1CEN LK 9POS	1
01 CGHV40180 1	L10	INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND	1
	Q1	CGHV40180	1

Product Dimensions CGHV40180P (Package Type – 440206)





NDTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.

2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.

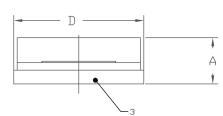
4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

	INCHES		MILLIMETERS		NOTES
DIM	MIN	MAX	MIN	MAX	
Α	0.125	0.145	3.18	3.68	
A1	0.057	0.067	1.45	1.70	
A2	0.035	0.045	0.89	1.14	
b	0.210	0.220	5.33	5.59	2x
с	0.004	0.006	0.10	0.15	2x
D	0.375	0.385	9.53	9.78	
D1	0.355	0.365	9.02	9.27	
E	0.400	0.460	10.16	11.68	
E1	0.225	0.235	5.72	5.97	
L	0.085	0.115	2.16	2.92	2x
α	45* REF		45'	REF	

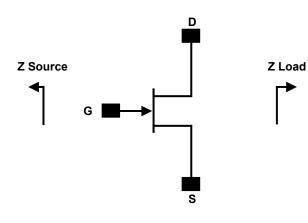
PIN 1. GATE

2. DRAIN

3. SOURCE



Source and Load Impedances



Frequency (MHz)	Z Source	Z Load
50	23.7 + J25.9	7.6 + J0.6
150	7.4 + J8.3	8.1 + J0.7
250	4.2 +J7.9	7.9 + J2.2
500	1.4 + J1.5	4.7 + J2.7
750	1.0 + J0.0	3.9 + J2.3
1000	0.7 + J1.1	4.0 + J1.8

Note 1. V_{DD} = 50 V, I_{DQ} = 1.0A in the 440206 package Note 2. Optimized for Power Gain, P_{SAT} and Drain Efficiency

Note 3. When using this device at low frequency, series resistor should be used to maintain amplifier stability

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Test Methodology
Human Body Model	НВМ	1A (> 250 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	2 (125 V to 250 V)	JEDEC JESD22 C101-C

Rev 1.3 - April 2020



Part Number System

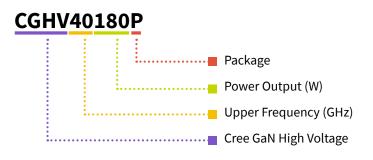


Table 1.

Parameter	Value	Units
Upper Frequency ¹	4.0	GHz
Power Output	180	W
Package	Flange	-

Note¹: Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Table 2.				
Character Code	Code Value			
A	0			
В	1			
С	2			
D	3			
E	4			
F	5			
G	6			
Н	7			
J	8			
К	9			
Examples:	1A = 10.0 GHz 2H = 27.0 GHz			

Table 2.







Order Number	Description	Unit of Measure	Image
CGHV40180P	GaN HEMT	Each	Contraction of the second
CGHV40180P-AMP	Test board with GaN HEMT(pill) installed	Each	



For more information, please contact:

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Sales Contact RFSales@cree.com

Notes

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